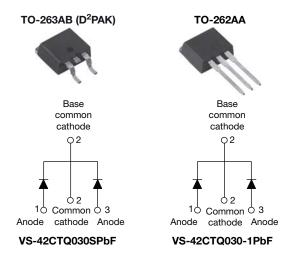
www.vishay.com

**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY					
I <sub>F(AV)</sub>	2 x 20 A				
V <sub>R</sub>	30 V				
V <sub>F</sub> at I <sub>F</sub>	0.38 V				
I <sub>RM</sub> max.	183 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13				
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA				
Diode variation	Common cathode				

### FEATURES

- 150 °C T<sub>J</sub> operation
- · Center tap configuration
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long
   term reliability



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	UNITS				
I <sub>F(AV)</sub>	Rectangular waveform	40	A			
V <sub>RRM</sub>		30	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1100	A			
V <sub>F</sub>	20 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.38	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-42CTQ030SPbF VS-42CTQ030-1PbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>					
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward per leg	1	50 % duty cyclo at $T_{-} = 121 $ °C	rootongular wayoform	20			
current, see fig. 5 per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 121$ °C, rectangular waveform		40			
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1100	A		
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>BBM</sub> applied	360			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 2.90 mH		13	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim	ro in 1 μs ium V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	3	А		

Revision: 15-Aug-15

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



# VS-42CTQ030SPbF, VS-42CTQ030-1PbF

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	T <sub>.1</sub> = 25 °C	0.48		
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 C	0.57		
	V FM (*)	20 A	T.I = 125 °C	0.38		
		40 A	1j = 125 C	0.51		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA	
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	183	ШA	
Threshold Voltage	V <sub>F(TO)</sub>			0.22	V	
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> =T <sub>J</sub> maximum		6.76	mΩ	
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	2840	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body 8.0 nH			nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µs				

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	YMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg		P		2.0		
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub> DC operation	1.0	°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approvimate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm	
				12 (10)	(lbf ⋅ in)	
Marking davias			Case style TO-263AB (D <sup>2</sup> PAK)	42CTC	030S	
warking device	Marking device		Case style TO-262AA	42CTQ	030-1	



## VS-42CTQ030SPbF, VS-42CTQ030-1PbF

**Vishay Semiconductors** 

25

30

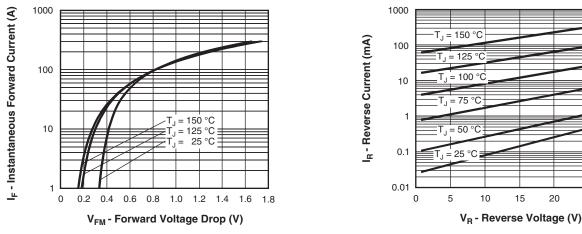


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

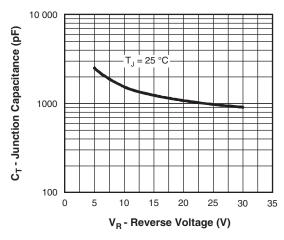
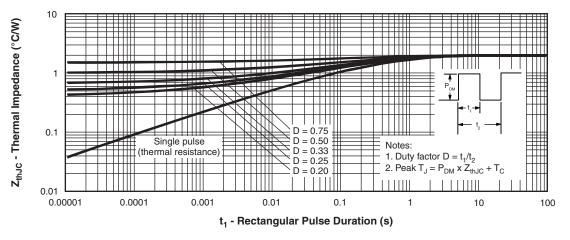


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





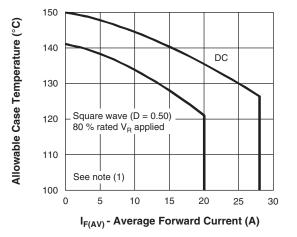
 Revision: 15-Aug-15
 3
 Document Number: 94221

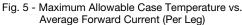
 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

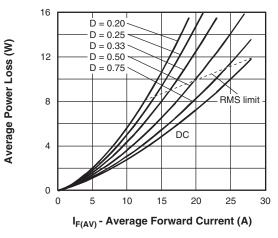


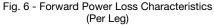
## VS-42CTQ030SPbF, VS-42CTQ030-1PbF

**Vishay Semiconductors** 









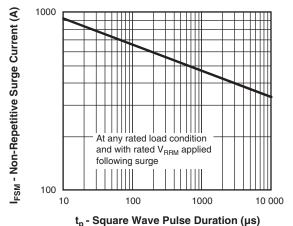
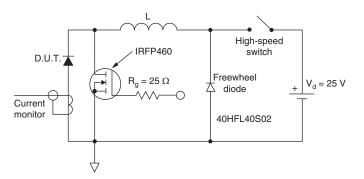




Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)





#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{10 V} \end{array}$

Revision: 15-Aug-15

4

Document Number: 94221

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

Revision: 15-Aug-15 Document Number: 94221 5 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

# VS-42CTQ030SPbF, VS-42CTQ030-1PbF

# Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

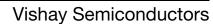
Device code	vs-	42	С	т	Q	030	S	TRL	PbF
		2	3	4	5	6	7	8	9
	1       -         2       -         3       -         4       -         5       -         6       -	<ul> <li>Circuit configuration: C = common cathode</li> <li>T = TO-220</li> <li>Schottky "Q" series</li> </ul>							
	7	- • S = D <sup>2</sup> PAK • -1 = TO-262							
	8 -	• TI	<ul> <li>None = tube (50 pieces)</li> <li>TRL = tape and reel (left oriented - for D<sup>2</sup>PAK only)</li> <li>TRR = tape and reel (right oriented - for D<sup>2</sup>PAK only)</li> </ul>						
	9 -			(Pb)-fre			eu - 101		Uniy)

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-42CTQ030SPBF	50	1000	Antistatic plastic tubes					
VS-42CTQ030STRRPBF	800	800	13" diameter plastic tape and reel					
VS-42CTQ030STRLPBF	800	800	13" diameter plastic tape and reel					
VS-42CTQ030-1PBF	50	1000	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046			
Dimensions	TO-262AA	www.vishay.com/doc?95419			
Part marking information		www.vishay.com/doc?95008			
Packaging information		www.vishay.com/doc?95032			



# **Outline Dimensions**

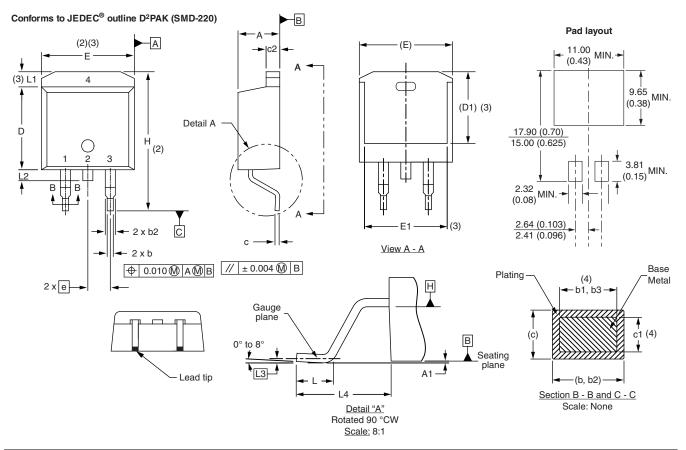


D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

www.vishay.com

ISHA



SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
с	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

(4) Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

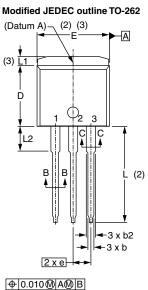


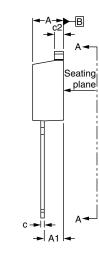
### **Outline Dimensions**

**Vishay Semiconductors** 

**TO-262** 

### **DIMENSIONS** in millimeters and inches

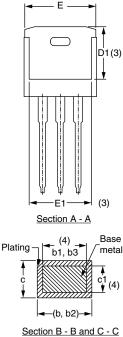




Lead assignments



**Diodes** 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



Scale: None

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.160 0.190 А 4.06 4.83 0.080 A1 2.03 3.02 0.119 0.51 0.99 0.020 0.039 b b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 с 0.38 0.58 0.015 0.023 c1 4 0.045 0.065 c2 1.14 1.65 D 9.65 8.51 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2.3 E1 7.90 8.80 0.311 0.346 3 2.54 BSC 0.100 BSC е L 13.46 0.530 0.555 14.10 L1 1.65 0.065 3 3.56 L2 3.71 0.140 0.146

### Notes

Revision: 04-Oct-10

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(4) Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Document Number: 95419 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

Downloaded from Arrow.com.

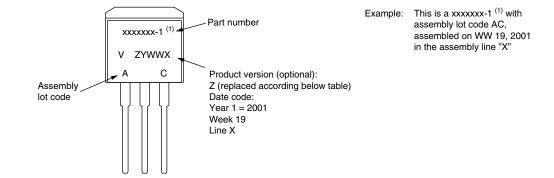
1



## **Part Marking Information**

### **Vishay Semiconductors**

**TO-262** 



### Note

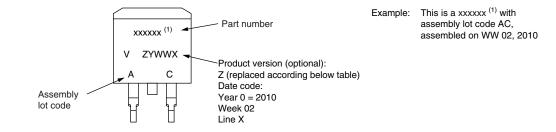
<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z) PRODUCT DEFINITION						
A	Termination lead (Pb)-free					
B Totally lead (Pb)-free						
E	RoHS-compliant and termination lead (Pb)-free					
F	RoHS-compliant and totally lead (Pb)-free					
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free					
N Halogen-free, RoHS-compliant and totally lead (Pb)-free						
G Green						



### **Vishay Semiconductors**

D<sup>2</sup>PAK



#### Note

<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION			
A	Termination lead (Pb)-free			
В	Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free			
F	RoHS-compliant and totally lead (Pb)-free			
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free			
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free			
G Green				

Revision: 21-Jun-17 1 Document Number: 95444 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.